

查询ARF676供应商

捷多邦，专业PCB打样工厂，24小时加急出货

ANSALDO

Ansaldo Trasporti s.p.a.
Unita' Semiconduttori

Via N. Lorenzi 8 - I 16152 GENOVA - ITALY
Tel. int. +39/(0)10 6556549 - (0)10 6556488
Fax Int. +39/(0)10 6442510
Tx 270318 ANSUSE I -

FAST RECOVERY DIODE

ARF676

Repetitive voltage up to **4800 V**
Mean forward current **1515 A**
Surge current **18 kA**

FINAL SPECIFICATION

feb 97 - ISSUE : 03

Symbol	Characteristic	Conditions	T _j [°C]	Value	Unit
BLOCKING					
V _{RRM}	Repetitive peak reverse voltage		140	4800	V
V _{RSM}	Non-repetitive peak reverse voltage		140	4900	V
I _{RRM}	Repetitive peak reverse current	V=VRRM	140	100	mA
CONDUCTING					
I _{F(AV)}	Mean forward current	180° sin ,50 Hz, Th=55°C, double side cooled		1515	A
I _{F(AV)}	Mean forward current	180° square,50 Hz,Th=55°C,double side cooled		1535	A
I _{FSM}	Surge forward current	Sine wave, 10 ms	140	18	kA
I ² t	I ² t	reapplied reverse voltage up to 50% VRSM		1620 x1E3	A²s
V _{FM}	Forward voltage	Forward current 1570 A	25	2.4	V
V _{F(TO)}	Threshold voltage		140	1.25	V
r _F	Forward slope resistance		140	0.500	mohm
SWITCHING					
t _{rr}	Reverse recovery time	I _F = 1000 A di/dt= 250 A/μs VR = 100 V	140	6	μs
Q _{rr}	Reverse recovery charge			2000	μC
I _{rr}	Peak reverse recovery current			800	A
s	Softness (s-factor), min			0.5	
V _{FR}	Peak forward recovery	di/dt= 400 A/μs	140	40	V
MOUNTING					
R _{th(j-h)}	Thermal impedance	Junction to heatsink, double side cooled		18	°C/kW
T _j	Operating junction temperature			-30 / 140	°C
F	Mounting force			22.0 / 24.5	kN
	Mass			300	g

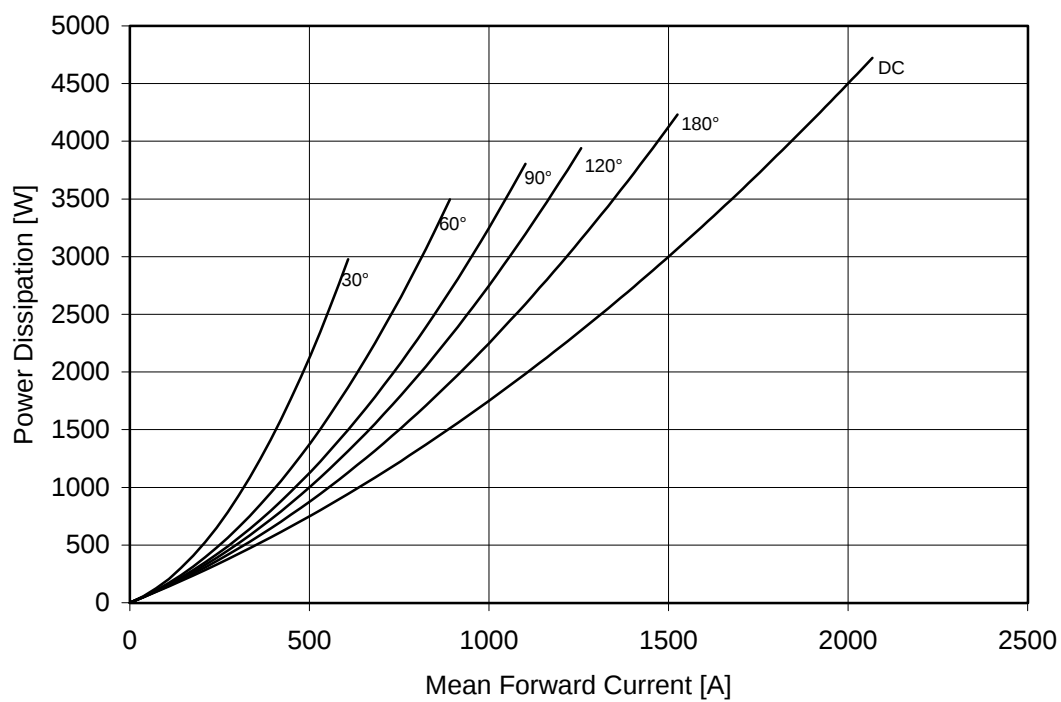
ORDERING INFORMATION : ARF676 S 48

standard specification ☐ VRRM/100 ☐

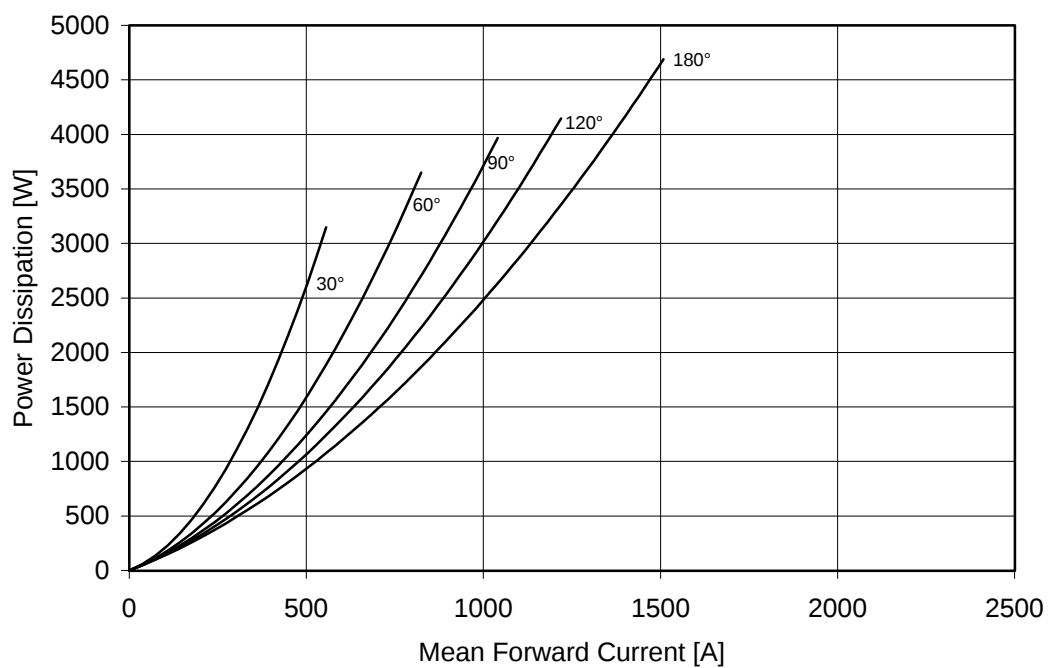


DISSIPATION CHARACTERISTICS

SQUARE WAVE

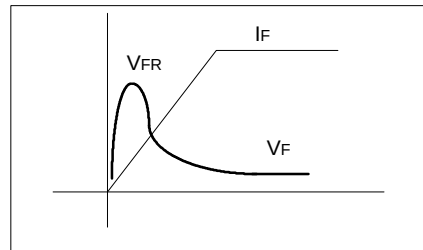
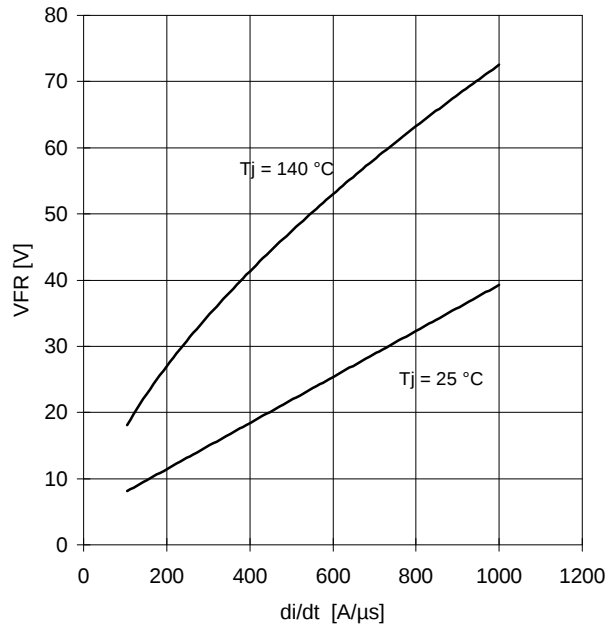


SINE WAVE



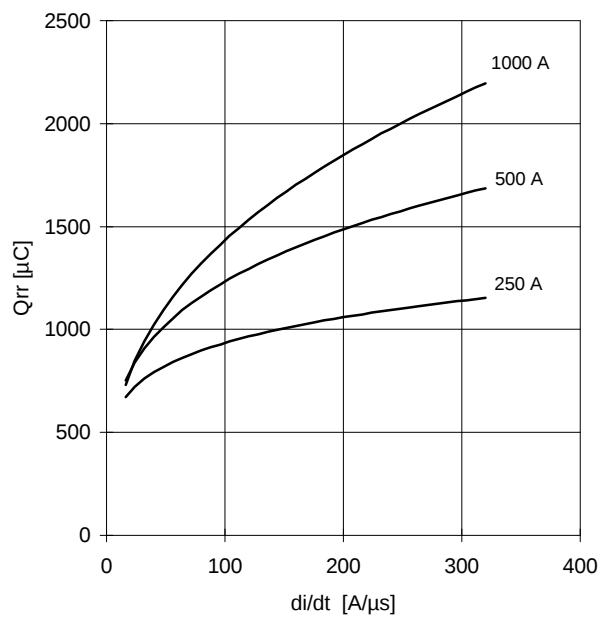
SWITCHING CHARACTERISTICS

FORWARD RECOVERY VOLTAGE



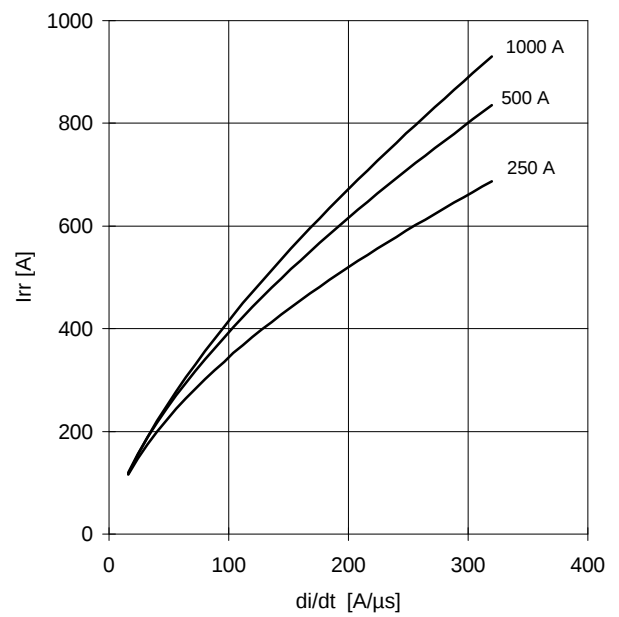
REVERSE RECOVERY CHARGE

$T_j = 140\text{ }^{\circ}\text{C}$



REVERSE RECOVERY CURRENT

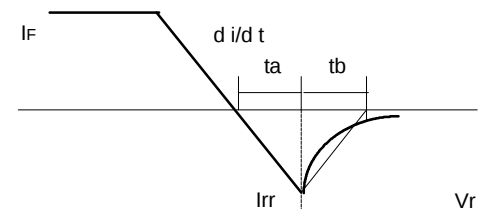
$T_j = 140\text{ }^{\circ}\text{C}$



$$t_a = I_{rr} / (di/dt) \quad t_b = t_{rr} - t_a$$

$$\text{Softness (s factor)} \quad s = t_b / t_a$$

$$\text{Energy dissipation during recovery } E_r = V_r \cdot (Q_{rr} - I_{rr} \cdot t_a / 2)$$

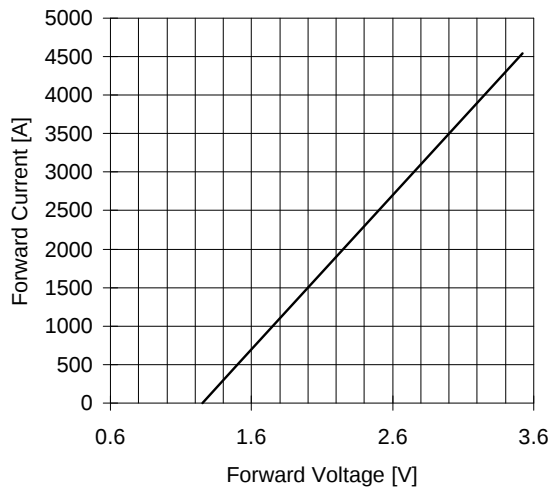


ARF676 FAST RECOVERY DIODE

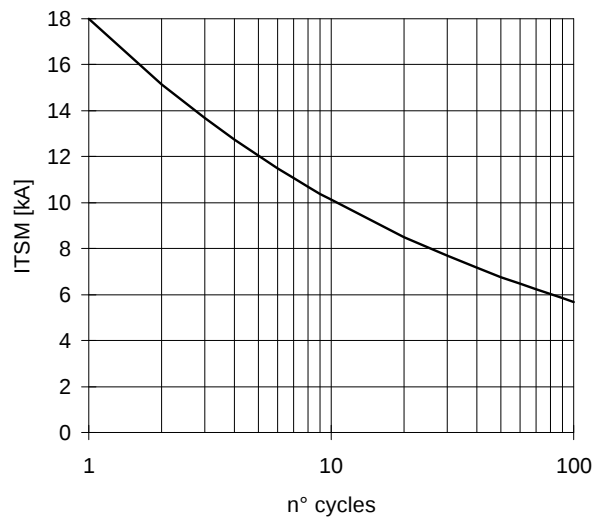
ANSALDO

FINAL SPECIFICATION feb 97 - ISSUE : 03

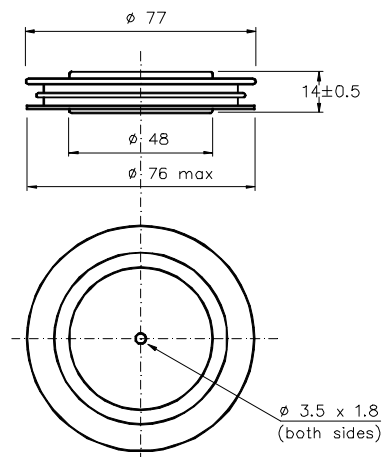
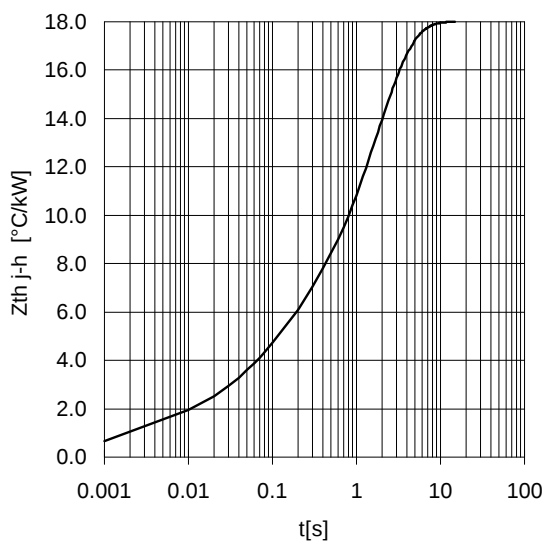
FORWARD CHARACTERISTIC
 $T_j = 140\text{ }^{\circ}\text{C}$



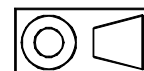
SURGE CHARACTERISTIC
 $T_j = 140\text{ }^{\circ}\text{C}$



TRANSIENT THERMAL IMPEDANCE
DOUBLE SIDE COOLED



Dimensions
in mm



All the characteristics given in this data sheet are guaranteed only with uniform clamping force, cleaned and lubricated heatsink, surfaces with flatness $< .03$ mm and roughness $< 2\text{ }\mu\text{m}$.

In the interest of product improvement ANSALDO reserves the right to change any data given in this data sheet at any time without previous notice.

If not stated otherwise the maximum value of ratings (symbols over shaded background) and characteristics is reported.

Distributed by

